

## KSD5041

### **AF Output Amplifier for Electronic Flash Unit**

- Low Collector-Emitter Saturation Voltage
- High Performance at Low Supply Voltage



## **NPN Epitaxial Silicon Transistor**

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	40	V
V <sub>CEO</sub>	Collector-Emitter Voltage	20	V
V <sub>EBO</sub>	Emitter-Base Voltage	7	V
I <sub>C</sub>	Collector Current	5	А
P <sub>C</sub>	Collector Power Dissipation	0.75	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

## **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =1mA, I <sub>B</sub> =0	20			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>C</sub> =10μA, I <sub>C</sub> =0	7			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =10V, I <sub>E</sub> =0			0.1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}$ =7V, $I_C$ =0			0.1	μΑ
h <sub>FE1</sub>	DC Current Gain	$V_{CE}$ =2V, $I_{C}$ =0.5A	180		600	
h <sub>FE2</sub>		V <sub>CE</sub> =2V, I <sub>C</sub> =2A	150			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =3A, I <sub>B</sub> =0.1A			1	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE}$ =6V, $I_{C}$ =50mA		150		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =20V, I <sub>E</sub> =0, f=1MHz			50	pF

## **h**<sub>FE</sub> Classification

Classification	Р	Q	R	
h <sub>FE</sub>	180 ~ 270	230 ~ 380	340 ~ 600	

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## **Typical Characteristics**

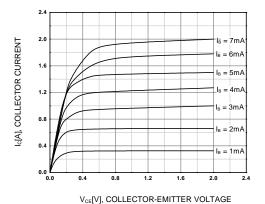


Figure 1. Static Characteristic

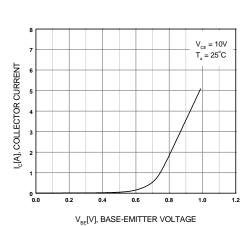


Figure 3. Base-Emitter Saturation Voltage

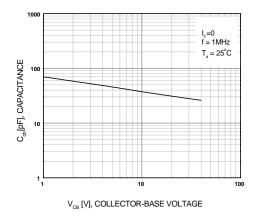


Figure 5. Collector Output Capacitance

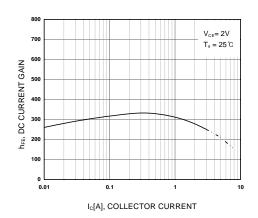


Figure 2. DC current Gain

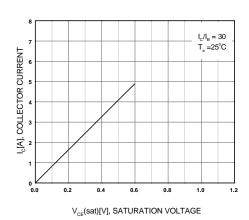


Figure 4. Collector-Emitter Saturation Voltage

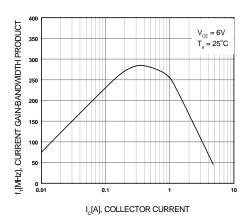


Figure 6. Current Gain Bandwidth Product

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# Typical Characteristics (Continued)

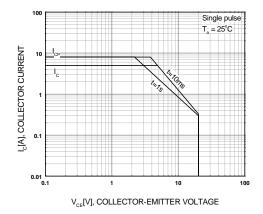


Figure 7. Safe Operating Area

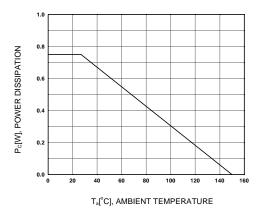
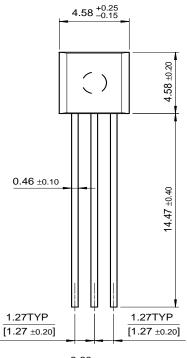


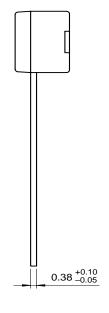
Figure 8. Power Derating

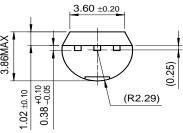
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# **Package Dimensions**

TO-92







Dimensions in Millimeters

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